

September 1983 Revised February 1999

MM74HC132

Quad 2-Input NAND Schmitt Trigger

General Description

The MM74HC132 utilizes advanced silicon-gate CMOS technology to achieve the low power dissipation and high noise immunity of standard CMOS, as well as the capability to drive 10 LS-TTL loads.

The 74HC logic family is functionally and pinout compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 12 ns
- Wide power supply range: 2V-6V
- Low quiescent current: 20 µA maximum (74HC Series)
- Low input current: 1 µA maximum
- Fanout of 10 LS-TTL loads
- Typical hysteresis voltage: 0.9V at V_{CC}=4.5V

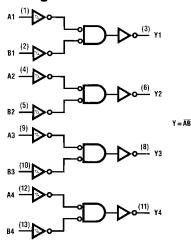
Ordering Code:

Order Number	Package Number	Package Description
MM74HC132M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
MM74HC132SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC132MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC132N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. (Tape and Reel not available in N14A.)

Connection Diagram

Logic Diagram



Absolute Maximum Ratings(Note 1)

DC Input Voltage (V_{CC})

DC Output Voltage (V_{IN})

-1.5 to V_{CC} +1.5V

DC Output Voltage (V_{OUT})

-0.5 to V_{CC} +0.5V

Clamp Diode Current (I_{IK} , I_{OK}) ± 20 mA DC Output Current, per pin (I_{OUT}) ± 25 mA DC V_{CC} or GND Current, per pin (I_{CC}) ± 50 mA Storage Temperature Range (T_{STG}) -65° C to +150 $^{\circ}$ C

Power Dissipation (P_D)

(Note 3) 600 mW S.O. Package only 500 mW

Lead Temperature (T_L)
(Soldering 10 seconds)

260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage	0	V_{CC}	V
(V_{IN}, V_{OUT})			

Operating Temperature Range (T_A) -40 +125 °C Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V	T _A =	25°C	T _A = -40 to 85°C	T _A = -40 to 125°C	Units
Symbol	Parameter	Conditions	v _{cc}	Тур	Guaranteed Limits			Units
V_{T+}	Positive Going	Min	2.0V		1.0	1.0	1.0	V
	Threshold Voltage		4.5V		2.0	2.0	2.0	V
			6.0V		3.0	3.0	3.0	V
		Max	2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{T-}	Negative Going	Min	2.0V		0.3	0.3	0.3	V
	Threshold Voltage		4.5V		0.9	0.9	0.9	V
			6.0V		1.2	1.2	1.2	V
		Max	2.0V		1.0	1.0	1.0	V
			4.5V		2.2	2.2	2.2	V
			6.0V		3.0	3.0	3.0	V
V _H	Hysteresis Voltage	Min	2.0V		0.2	0.2	0.2	V
			4.5V		0.4	0.4	0.4	V
			6.0V		0.5	0.5	0.5	V
		Max	2.0V		1.0	1.0	1.0	V
			4.5V		1.4	1.4	1.4	V
			6.0V		1.5	1.5	1.5	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	2.0	1.9	1.9	1.9	V
	Output Voltage	$ I_{OUT} \leq 20 \; \mu A$	4.5V	4.5	4.4	4.4	4.4	V
		$V_{IN} = V_{IH}$ or V_{IL}	6.0V	6.0	5.9	5.9	5.9	V
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}	2.0V	0	0.1	0.1	0.1	V
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	4.5V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$ or V_{IL}	6.0V	0	0.1	0.1	0.1	V
		$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I _{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μΑ
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		2.0	20	40	μΑ
	Supply Current	$I_{OUT} = 0 \mu A$						
						1	1	

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{O2}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

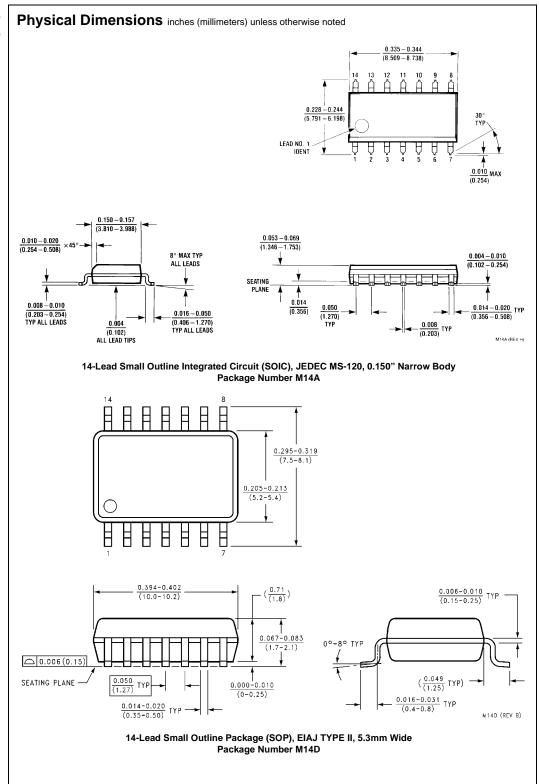
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay		12	20	ns

AC Electrical Characteristics

 $V_{CC} = 2.0 \text{V}$ to 6.0V, $C_L = 50 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$ (unless otherwise specified)

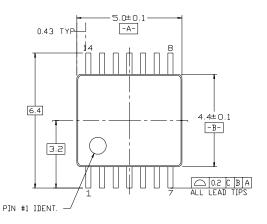
Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Units
				Тур	Typ Guaranteed Limits			Units
t_{PHL}, t_{PLH}	Maximum		2.0V	63	125	158	186	ns
	Propagation Delay		4.5V	13	25	32	37	ns
			6.0V	11	21	27	32	ns
t_{TLH} , t_{THL}	Maximum Output		2.0V	30	75	95	110	ns
	Rise and Fall Time		4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C _{PD}	Power Dissipation	(per gate)		130				pF
	Capacitance (Note 5)							
C _{IN}	Maximum Input Capacitance				5	10	10	pF

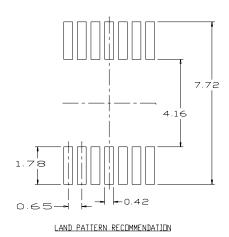
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC}^{\ f} + I_{CC}$.

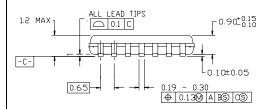


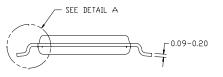
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

14LD, TSSOP, JEDEC MO-153, 4.4MM WIDE



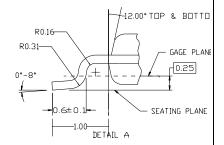






NOTES

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION ABJREF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14

Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.740 - 0.770 (18.80 - 19.56)0.090 (2.286) 14 13 12 11 10 9 8 14 13 12 INDEX AREA 0.250 ± 0.010 (6.350 ± 0.254) PIN NO. 1 IDENT PIN NO. 1 IDENT 1 2 3 4 5 6 7 1 2 3 $\frac{0.092}{(2.337)}$ DIA $\frac{0.030}{(0.762)}$ MAX DEPTH OPTION 1 OPTION 02 $\frac{0.135 \pm 0.005}{(3.429 \pm 0.127)}$ 0.300 - 0.320 $\frac{0.630 - 8.128}{(7.620 - 8.128)}$ 0.060 (1.524) 0.145 - 0.2004° TYP Optional (1.651) (3.683 - 5.080) $\frac{0.008 - 0.016}{(0.203 - 0.406)}$ TYP 0.020 (0.508) 0.125 - 0.150 0.075 ± 0.015 $\overline{(3.175 - 3.810)}$ (1.905 ± 0.381) (7.112) MIN 0.014 -- 0.023 0.100 ± 0.010 (2.540 ± 0.254) (0.356 - 0.584) $\frac{0.050 \pm 0.010}{(1.270 - 0.254)} \text{ TYP}$ 0.325 ^{+0.040} -0.015 8.255 + 1.016 N14A (REV F)

14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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